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TH 9808PA 1" VIDICON

- MAGNETIC FOCUS AND DEFLECTION
- HIGH RESOLUTION (1000 T.V. LINES)
 - NORMAL SENSITIVITY
 - LOW LAG
- HIGH QUALITY INDUSTRIAL C.C.T.V.

TH 9808PA is a 1" Vidicon designed especially for pick-up in high quality TV camaras (black and white or color TV camaras). This tube incorporates in its structure the latest isolated post-acceleration electrode with separate mesh connection. Due to this feature TH 9808PA provides higher resolution, higher output signal capability and better resolution and signal uniformity than previous Vidicons tubes.

TH 9808PA is intended for all industrial T.V. applications and specially for normal light level condition: the quality of image is satisfactory for 10 lux (1fc) scene illumination.

The sensitivity of TH 9808PA can be equivalent to photographic film having an ASA exposure index of 1200 (32/ 10 DIN, 39 Sch). Satisfactory quality picture with good resolution and acceptable signal to noise ratio can be obtained at illumination of 0. 5 lux (50 mf.c) to 1 lux (100 mf.c) on the faceplate (5 to 10 lux on the subject with an unity numerical aperture lens) giving rise to a signal current of 50 nA at 50 nA dark current. For such illuminations higher signal current is obtained by increasing dark current up to 100 nA, value beyond which a signal saturation will occur.



Due to a new low lag photoconductive layer excellent quality of picture can be obtained within a large illumination range with good signal uniformity and appropriate "gamma" characteristics.

TH 9808PA performances are substantially identical under high or low level illumination conditions. Tube sensitivity can be controlled by target voltage which also causes some variation of dark current.

TH 9808PA can be operated over a wide range of electrode voltage selection although recommended adjustment requires a g4 voltage to g3 voltage ratio of 1.4-1.5. Under these conditions TH 9808PA can provide an optimum resolution and an uniform signal output over the entire scanned area with a beam landing considerably improved minimizing "porthole" effect and geometrical distortion.

The limiting resolution of TH 9808PA is about 1000 T.V. lines at center of picture and 600 T.V. lines at corner. This high resolution is obtained with 900 V on electrode g4 and 600 V on g3. When the TH 9808PA is operated at a lower g4 voltage of 500 V and g3 voltage of 300 V, its limiting resolution will be 900 T.V. lines at center and 500 T.V. lines at corner. Operating g4 voltage at 1.5 times g3 voltage requires 20% deflection current increase over current necessary for g3 - g4 connected mode. Focusing field is not noticeably changed with such an operation.

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unipotential

60 g

Full advantage of resolution and signal uniformity is achieved when deflecting and focusing components are properly designed and when the tube is correctly located inside. The thickness of the photoconductive layer is made very uniform and allows for constant output signal and constant dark current. When landing error due to imperfect scanning system is present, the voltage gradient across the photoconductive layer is not uniform and a signal variation (shading) is introduced which can be compensated by proper adjustment of the cathode, g1 and g2 voltages.

Due to good design, high reliability is obtained throughout the tube life. Requirement for alignment field is reduced to a minimum by precise electron gun mounting. An extremely flat faceplate avoids all optical distortions and allows for the use of any good quality lens. Particle barriers adjacent to the field mesh allows these tubes to operate in any position.

One watt power heater makes these Vidicons particularly suitable for transistorized equipment. The reduced heat dissipation improves the quality of the picture by lowering faceplate temperature.

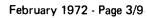
GENERAL CHARACTERISTICS

Electrical

Cathode

	indirectly heated oxide coated		
Heater:			
- voltage	6. 3		V
- current at 6. 3 V	0. 13!	5 to 0.	165 A
Minimum preheating time	60		s
Output capacitances :			
- target to all other electrodes	4. 5		pF
Spectral response	see curve		e
Focusing method	magnetic		С
Deflection method	magnetic		С
Mechanical			
Overall length max.	164	mm	(6. 46")
Overall diameter max.	. 29	mm	(1. 14'')
Bulb diameter	26. 7	mm	(1. 03'')
Base diameter		E 9 C	. •
	(JEDE		•
Socket (note 1)	METO	X N° 30	0. 250
Deflecting yoke - Focusing coil assembly (note 2)	GERHARD type BV 200 - 1k1		
Alignment coil (note 2)	GERHAR	D type	BV 80/3
or Deflecting yoke - Focusing coil - Alignment coil			
assembly (note 2)	CLEVELAND	type \	/YFA - 355.2
Photoconductive layer :			
- normal dimensions of image on target	12. 7 m	ım x 9.	
- maximum useful diagonal diameter (4 x 3 aspect ratio).	17		mm
- orientation of quality rectangle:			
horizontal scan parallel to the plane passing through the			
tube axis and short index pin (note 3)			
Mounting position		any	

Net weight, approximate





OPERATING CONDITIONS

(All potentials are referred to cathode)

Maximum ratings: (absolute values)		
Electrode g4 voltage (post-acceleration electrode)	1 000	V
Electrode g3 voltage (wall electrode)	1 000	V
Electrode g2 voltage (accelerator)	350	V
Electrode g1 voltage (electrode for picture cut-off):		
- negative bias value	150	V
- positive bias value	0	V
Heater voltage max.	6. 9	V
min .	5. 7	V
Peak heater cathode voltage:		
- heater negative with respect to cathode	125	V
- heater positive with respect to cathode	10	V
Target voltage	125	V
Dark current	0. 20	μΑ
Peak target current (note 4)	0.60	μΑ
Faceplate:		
- illumination	10 000	lux
	or 1000	fc
- temperature	70	°C

Operational conditions

Scanned area 12. 7 mm x 9. 5 mm Faceplate temperature 25 °C (note 5)

Electrode voltage modes :	Low	Intermedia	te High	
Electrode g4 voltage	300	500	900	٧
Electrode g3 voltage	180	300 to 350	600	V
Electrode g2 voltage	300	300	300	V
Electrode g1 (note 6)	-45 to -110	-45 to -110	-45 to -110	V
Average 'gamma' for a target illumination:				
between 1 and 100 lux (note 7)	0. 65	0.65	0. 65	
Minimum blanking peak to peak voltage:				
- applied to electrode g1	- 75	- 75	– 75	V
- applied to cathode	+ 20	+ 20	+ 20	V
Limiting resolution at center of picture (note 8)	800	900	1 000	TV lines
Limiting resolution at corner of picture	400	500	600	TV lines
M.T.F. response at 400 T.V. lines at center of				
picture (5 MHz-625 CCIR standard) (note 9) .	30	40	50	%
Field strength at center of focusing coil	30 ± 2	40 ± 2	50 ± 2	Gauss
Peak deflecting coil current :				
- horizontal	130	170	200	mΑ
- vertical	15	20	24	mA
Field strength of alignment coil	0 to 4	0 to 4	0 to 4	Gauss

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Typical performance

1 - HIGH LIGHT LEVEL OPERATION

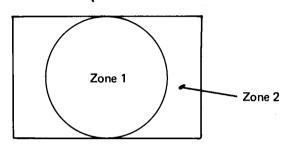
(Faceplate illumination 100 lux or 10 fc)

(, 234)		
Doub summer !	5	nA
Dark current io	10 to 25	V
Target voltage for i _o = 5 nA (note 10)	10 to 25	lux
raceplate illumintation (2004 K) (note 11)	or 10	fc
Signal current	300	nΑ
- maximum	15	%
- average	10	%
2 - AVERAGE SENSITIVITY OPERATION	1	
(Faceplate illumination 10 lux or 1 fc)		
Dark current io	20	nA
Target voltage for $i_0 = 20 \text{ nA}$ (note 10)	20 to 50	V
Faceplate illumination (2854 K) (note 11)	10	lux
	or 1	fc
Signal current	180	nA
Corresponding sensitivity	150	μA/Im
Target illumination for 100 nA signal current	3	lux
	or 300	mfc
Lag: (note 12)	20	۰,
- maximum	20	%
- average	12	%
3 - HIGH SENSITIVITY OPERATION		
(Faceplate illumination 5 lux or 500 fc)		
Doub compand:	EO	^
Dark current io	50	nA V
Target voltage for i = 50 nA (note 10)	25 to 60	V
Target voltage for i _O = 50 nA (note 10)	25 to 60 500	V mfc
Target voltage for i _o = 50 nA (note 10)	25 to 60 500 200	V mfc nA
Target voltage for i _o = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity	25 to 60 500 200 350	V mfc nA μA/Im
Target voltage for i _o = 50 nA (note 10)	25 to 60 500 200 350 1.5	V mfc nA μA/Im lux
Target voltage for i _o = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current	25 to 60 500 200 350	V mfc nA μA/Im
Target voltage for i _O = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12)	25 to 60 500 200 350 1. 5 or 150	V mfc nA μA/Im lux mfc
Target voltage for i _O = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum	25 to 60 500 200 350 1. 5 or 150	V mfc nA μA/Im lux mfc
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Target voltage for i _O = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum - average 4 - VERY HIGH SENSITIVITY OPERATIO	25 to 60 500 200 350 1. 5 or 150 20	V mfc nA μA/Im lux mfc
Target voltage for i _O = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum - average	25 to 60 500 200 350 1. 5 or 150 20	V mfc nA μA/Im lux mfc
Target voltage for i _o = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum - average 4 - VERY HIGH SENSITIVITY OPERATIO (Faceplate illumination 1 lux or 100 mfc)	25 to 60 500 200 350 1. 5 or 150 20 15	V mfc nA μA/Im lux mfc %
Target voltage for i _O = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum - average 4 - VERY HIGH SENSITIVITY OPERATIO (Faceplate illumination 1 lux or 100 mfc) Dark current i _O	25 to 60 500 200 350 1. 5 or 150 20 15	V mfc nA μA/Im lux mfc % %
Target voltage for i _O = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum - average 4 - VERY HIGH SENSITIVITY OPERATIO (Faceplate illumination 1 lux or 100 mfc) Dark current i _O	25 to 60 500 200 350 1. 5 or 150 20 15 ON	V mfc nA μA/Im lux mfc % %
Target voltage for i = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum - average 4 - VERY HIGH SENSITIVITY OPERATIO (Faceplate illumination 1 lux or 100 mfc) Dark current i = 100 nA (note 10) Faceplate illumination (2854 °K) (note 11)	25 to 60 500 200 350 1. 5 or 150 20 15 ON	V mfc nA μA/Im lux mfc % %
Target voltage for i = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum - average 4 - VERY HIGH SENSITIVITY OPERATIO (Faceplate illumination 1 lux or 100 mfc) Dark current i = 100 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current	25 to 60 500 200 350 1.5 or 150 20 15 ON	V mfc nA μA/Im lux mfc % %
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Target voltage for i = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum - average 4 - VERY HIGH SENSITIVITY OPERATIO (Faceplate illumination 1 lux or 100 mfc) Dark current i = 100 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current	25 to 60 500 200 350 1.5 or 150 20 15 NN 100 30 to 70 100 100 800 0.3	V mfc nA μA/Im lux mfc % % nA V mfc nA μA/Im lux
Target voltage for i = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum - average 4 - VERY HIGH SENSITIVITY OPERATIO (Faceplate illumination 1 lux or 100 mfc) Dark current i	25 to 60 500 200 350 1.5 or 150 20 15 ON 100 30 to 70 100 100 800	V mfc nA μA/Im lux mfc % % nA ν mfc nA μA/Im
Target voltage for i = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum - average 4 - VERY HIGH SENSITIVITY OPERATIO (Faceplate illumination 1 lux or 100 mfc) Dark current i = 100 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 50 nA signal current Lag: (note 12)	25 to 60 500 200 350 1.5 or 150 20 15 ON 100 30 to 70 100 100 800 0.3 or 30	V mfc nA μA/Im lux mfc % % nA V mfc nA μA/Im lux
Target voltage for i = 50 nA (note 10) Faceplate illumination (2854 °K) (note 11) Signal current Corresponding sensitivity Target illumination for 100 nA signal current Lag: (note 12) - maximum - average 4 - VERY HIGH SENSITIVITY OPERATIO (Faceplate illumination 1 lux or 100 mfc) Dark current i	25 to 60 500 200 350 1.5 or 150 20 15 NN 100 30 to 70 100 100 800 0.3	V mfc nA μA/Im lux mfc % % nA V mfc nA μA/Im lux



SPURIOUS SIGNAL TEST

The test is performed using a uniformly diffused white test pattern that is separated into two zones as shown in drawing.



The tube is operated under "Typical Operation" with a dark current of 20 nanoamperes and the lens adjusted to provide a signal current of 200 nanoamperes.

Spurious signals are classified by their size which is measured in percent of raster height.

Will actually be considered as defects, blemishes of contrast greater than 50% (note 12).

Allowable spot size for each zone is shown in table :

	Number Allowed			
*Ratio D / H (Percent raster height)	Zone 1 + Zone 2		2	
		a	a+b	a +b +c
a : 0.8% < D/H ≤ 1%	0	1		
b : 0.6% < D/H ≤ 0.8%	1		3	6
c : 0.2% < D/H ≤ 0.6%	3			

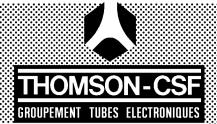
0. 2 % and under: do not count spots of this size unless concentration causes a smudge appearance

* D : average diameter of spot

H: raster height

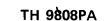
Smudges, streaks, mottled or grainy background having a contrast ratio greater than 15% constitute a reject.

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NOTES

- 1 METOX 86, rue de Villiers de l'isle Adam PARIS 20ème Téléphone : 636. 31-10.
- GERHARD KG REICHELSHEIM/ODW Germany.
 CLEVELAND ELECTRONICS Inc. 2000 Highland Road TWINSBURG OHIO 44 087.
- 3 It is necessary to assure correct positioning of the tube inside the coils. An immediate test consists in observing the fine mesh grid, the wires of which should be inclined 45° with respect to scanning. Then again the front end of the deflecting yoke should be positioned at 20 mm from the tube faceplate.
- 4 Target current is defined as total current in load resistance connected to target electrode: signal current plus dark current, dark current being the current left when illumination is subtracted. Video amplifiers must be designed properly to handle peak target current of 0.6 μ A to avoid amplifier overload and picture distortion.
- All these characteristics are provided for a temperature of faceplate of 25 °C, the temperature range recommended is within 20 to 30 °C. The rise of faceplate temperature is a function of ambient temperature, thermic dissipation of ambient devices and of the tube itself. Consequently, 10 °C of faceplate temperature rise implies a dark current multiplied by a factor of 2.
- 6 Without blanking pulses applied on electrode g1.
- Average "gamma" should be defined as the slope of the rectilinear part of transfer characteristics in log coordinates.
- Practically, limiting resolution corresponds to the resolution measured with twin bar test card with a modulation ratio of about 7%.
- For 625 lines C.C.I.R. standard, line duration being 52 μs (line suppression period not included), 400 TV lines correspond to 5 MHz.
- Indicated range of each type of service serves only to illustrate the operating target voltage range normally
 encountered. The target voltage for each Vidicon must be adjusted to that value which gives the designed
 operating dark current.
- 11 All the above mentioned illumination assume 2854 °K incandescent tungsten source.
- Lag is defined as the ratio of residual signal current measured 60 milliseconds after light excitation being removed to the initial signal current; this value assumes 50 field/second scanning rate.
- 13 Contrast is defined as : 100 x increment in video current due to blemish normal signal current



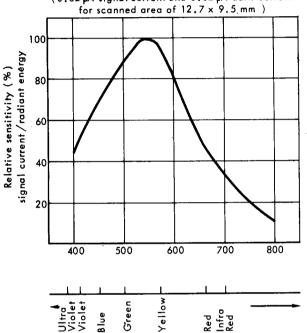
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Figure 1

TYPICAL SPECTRAL SENSITIVITY CHARACTERISTICS

For equal values of signal current at all wavelengths (0.02 μA signal current and 0.02 μA dark current for scanned area of 12.7 x 9.5 mm)



Wavelength (nm)

Figure 2

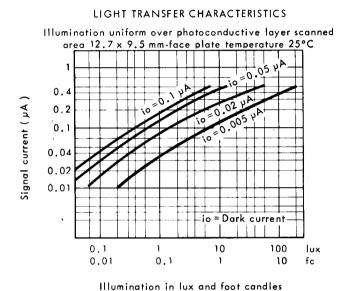
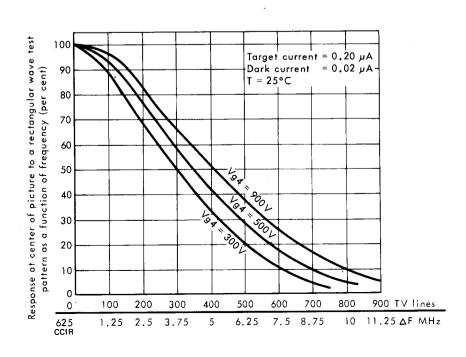


Figure 3 MODULATION TRANSFER FUNCTION



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Figure 4

RANGE OF DARK CURRENT

Scanned area of photoconductive layer 12.7 mm x 9.5 mm

0.2

0.1

0.05

0.02

0.01

0.005

T = 25°C

Target voltage (V)

40 60

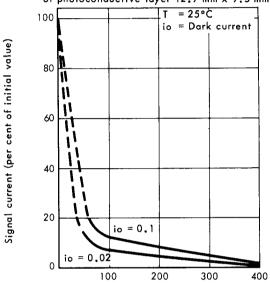
20

10

Figure 5

TYPICAL PERSISTENCE CHARACTERISTICS

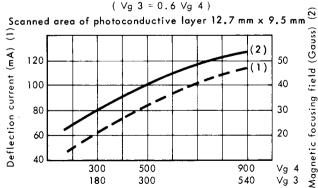
Initial highlight signal current of 0.2 μ A scanned area of photoconductive layer 12.7 mm \times 9.5 mm



Time after illumination is removed (ms)

Figure 6

- (1) Deflection current as a function of electrode g3 and g4 voltages(Vg 3 = 0.6 Vg 4)
- (2) Magnetic field at center of focusing coil (Vg 3 = 0.6 Vg 4)



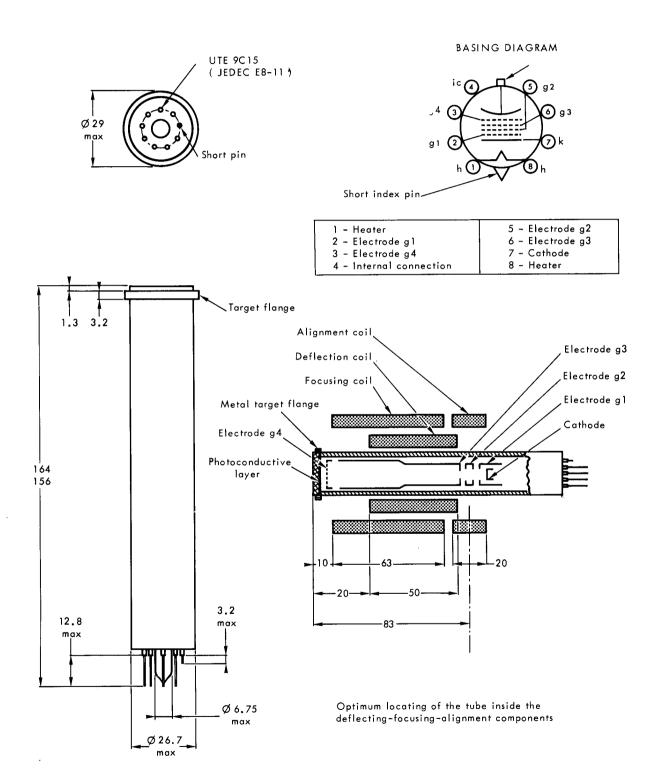
Electrode g3 and g4 voltages (V)

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OUTLINE DRAWING



Dimensions in mm.





